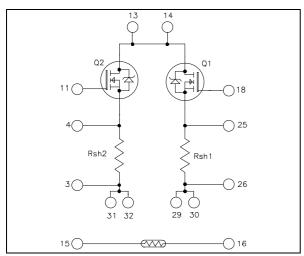
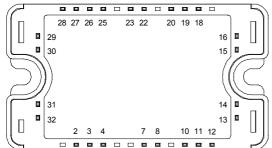


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Linear MOSFET Power Module





Pins 13/14; 29/30; 31/32 must be shorted together

$V_{DSS} = 100V$ $R_{DSon} = 09m\Omega$ typ @ Tj = 25°C $I_D = 154A*$ @ Tc = 25°C

Application

• Electronic load dedicated to power supplies and battery discharge testing

Features

- Linear MOSFET
- Very low stray inductance
- Internal thermistor for temperature monitoring
- High level of integration
- AlN substrate for improved thermal performance

Benefits

- Direct mounting to heatsink (isolated package)
- easy series and parallels combinations for power and voltage improvements
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- RoHS Compliant

Absolute maximum ratings (per leg)

Symbol	Parameter Parameter		Max ratings	Unit
$V_{ m DSS}$	Drain - Source Breakdown Voltage		100	V
$T_c =$		$T_c = 25^{\circ}C$	154*	
I_D	Continuous Drain Current	$T_c = 80$ °C	115*	A
I_{DM}	Pulsed Drain current		430	
V_{GS}	Gate - Source Voltage		±30	V
R_{DSon}	Drain - Source ON Resistance		10	mΩ
P_{D}	Maximum Power Dissipation \bullet $T_c = 25^{\circ}C$		480	W
I_{AR}	Avalanche current (repetitive and non repetitive)		100	A
E_{AR}	Repetitive Avalanche Energy		50	mJ
E_{AS}	Single Pulse Avalanche Energy		3000	1113

^{*} Output current per leg must be limited to 67A @ T_c =25°C and 47A @ T_c =80°C to not exceed the shunt specification. In addition the current capability must be limited to 75A on pins 13/14 to not exceed current capability of the pins.

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com

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[•] In saturation mode



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All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics (per leg)

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit	
I_{DSS}	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 100V$	$T_j = 25^{\circ}C$			100	4	
		$V_{GS} = 0V, V_{DS} = 80V$	$T_j = 125$ °C			500	μΑ	
R _{DS(on)}	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 69.5A$			9	10	mΩ	
V _{GS(th)}	Gate Threshold Voltage	$V_{GS} = V_{DS}$, $I_D = 2.5 \text{mA}$		2		4	V	
I_{GSS}	Gate – Source Leakage Current	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0$	V			±100	nA	

Dynamic Characteristics (per leg)

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
C_{iss}	Input Capacitance	$V_{GS} = 0V$		9875		
C_{oss}	Output Capacitance	$V_{\rm DS} = 25V$		3940		pF
C_{rss}	Reverse Transfer Capacitance	f = 1MHz		1470		

Shunt Electrical Characteristics (per leg)

Symbol	Characteristic		Min	Typ	Max	Unit
R_{sh}	Resistance value			4.4		mΩ
T_{sh}	Tolerance			2		%
P_{sh}	L Oad capacity	T _C =25°C			20	W
		T _C =80°C			10	VV
I_{sh}	Current capacity	T _C =25°C			67	٨
		T _C =80°C			47	A

Temperature sensor PTC

1 chipci	ature sensor r re					
Symbol	Characteristic		Min	Typ	Max	Unit
R ₂₅	Resistance @ 25°C		1980		2020	Ω
R_{100}/R_{25}	Resistance ratio	Tamb=100°C & 25°C	1.676	1.696	1.716	
R_{-55}/R_{25}	Resistance ratio	Tamb=-55°C & 25°C	0.48	0.49	0.50	
В	Temperature coefficient			7900		ppm/K

Thermal and package characteristics

Symbol	Characteristic			Min	Typ	Max	Unit
R_{thJC}	Junction to Case Thermal Resistance MOSFET (per leg)					0.26	°C/W
V_{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
T_{J}	Operating junction temperature range			-40		150	
T_{STG}	Storage Temperature Range			-40		125	°C
$T_{\rm C}$	Operating Case Temperature			-40		100	
Torque	Mounting torque	To heatsink	M4	2		3	N.m
Wt	Package Weight					110	g

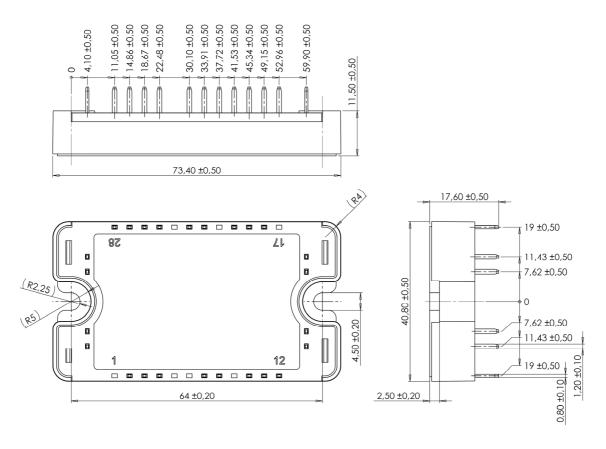
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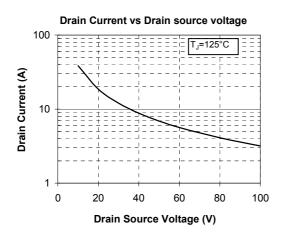
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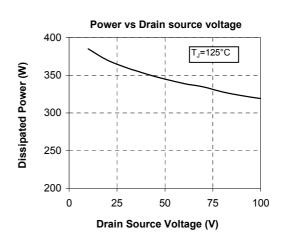
SP3 Package outline (dimensions in mm)



See application note 1901 - Mounting Instructions for SP3 Power Modules on www.microsemi.com

Typical Performance Curve (linear mode) (per leg)





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